TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

T 6 L 1 2

GATE DRIVER FOR TFT LCD PANELS

The T6L12 is a 256-channel output gate driver for TFT LCD panels. Since this device accepts external input of the panel drive voltage, allowing you to change the lowlevel output voltage. thus, this device can be used for various TFT LCD panel drive systems.

The T6L12 offers high integration circuit due to CMOS technology.

FEATURES

LCD drive output pins : 256 pins

LCD drive voltage : Max V_{SS} + 42 V

Data transfer method : Bidirectional shift register

Operating temperature : -20 to 75°C

Package : Tape carrier package (TCP)

Unit: mm **USER AREA** T6L12 PITCH IN 8.0 0.12 (SAM, 6FS)

Please contact Toshiba or a distributor for the latest TCP specification and product line-up.

TCP (Tape Carrier Package)

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Polyimide base film is hard and thin. Be careful not to injure yourself on the film or to scratch any other parts with the film. Try to design and manufacture products so that there is no chance of users touching the film after assembly, or if they do , that there is no chance of them injuring themselves. When cutting out the film, try to ensure that the film shavings do not cause accidents. After use, treat the leftover film and reel spacers as industrial waste.

Light striking a semiconductor device generates electromotive force due to photoelectric effects. In some cases this can

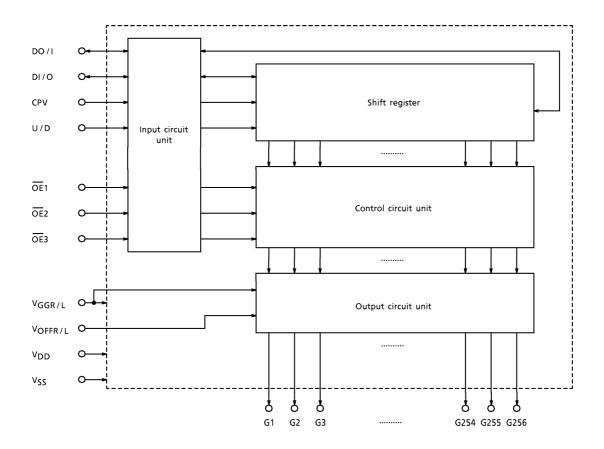
cause the device to malfunction. This is especially true for devices in which the surface (back), or side of the chip is exposed. When designing circuits, make sure that devices are protected against incident light from external sources. Exposure to light both during regular operation and during inspection must be taken into account.

The products described in this document are subject to the foreign exchange and foreign trade laws.

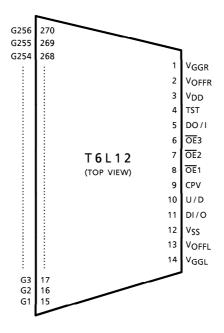
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BLOCK DIAGRAM



PIN ASSIGNMENT



The above diagram shows the device's pin configuration only and does not necessarily correspond to the pad layout on the chip. Please contact Toshiba or our distributors for the latest TCP specification.

PIN FUNCTION

PIN NAME	1/0	FUNCTION						
		Vertical shift data I/O pins These pins are used to input and output shift data. These pins are switched between input and output by setting the U/D pin as shown below.						
			U/D	DI/O	DO/I			
			Н	Input	Output	1		
			L	Output	Input			
DI/O	1/0	When set for inp	ut		•	•		
DO/I	170	This pin is use LCD driver. Th CPV. When set for out When two or	d to feed dat e data is latch put more T6L12s	ned into the sare cascaded,	shift registers this pin outp	the first stage of the at the rising edge of uts the data to be fed usly with the falling		
U/D	Input	This pin specific registers. The shift registers as follows: When U/D G1→G2→ When U/D G256→G25 The voltage a	The shift register data is shifted synchronously with each rising edge of CPV					
CPV	Input	Vertical shift clock This is the shift clock for the shift registers. Data is shifted through the shift registers synchronously with the rising edge of CPV.						
OE1 to 3	Input	Output enable pins These signals control the data appearing at the LCD panel drive pins (G1 through G256). The VOFFR/L voltage is output when OE1 to 3 are high; normal shift data is output when OE1 to 3 are low.						
V _{OFFR} V _{OFFL}	Input	Analog input pins These pins accept as their input the OFF level at the LCD panel drive pins (G1 through G256). Make sure that the same voltage is supplied to VOFFR and VOFFL.						

PIN NAME	1/0	FUNCTION
G1 to 256	Output	LCD panel drive pins These pins output the shift register data or the voltage applied to V_{GGR}/L or V_{OFFR}/L depending on the control signals $\overline{OE}1$ to 3.
V _{GGR} V _{GGL}	_	Power supply for LCD drive Make sure that the same voltage is supplied to $V_{\hbox{GGR}}$ and $V_{\hbox{GGL}}$.
V_{DD}	_	Power supply for the internal logic
V _{SS}	_	Power supply for LCD drive and internal logic

DEVICE OPERATION (see timing diagram)

(1) Shift data transfer method

U/D PIN	SHIFT	DATA	DATA TRANSFER METHOD		
	INPUT	OUTPUT	DATA TRANSFER WETHOD		
Н	DI/O	DO/I	$G1 \rightarrow G2 \rightarrow G3 \rightarrow G4 \rightarrow \cdots \rightarrow G256$		
L	DO/I DI/O		$G256 \rightarrow G255 \rightarrow G254 \rightarrow \cdots \rightarrow G1$		

The input data is latched into the internal register synchronously with the rising edge of the shift clock CPV. At the same time that the data is shifted to the next register at the next rise of CPV, new vertical shift data is latched into.

In the output operation, the data in the last shift register (G256 or G1) is output synchronously with the falling edge of CPV. (The output high voltage is the V_{DD} level; the output low voltage is the V_{SS} level.)

(2) LCD panel drive outputs

The LCD panel drive outputs are controlled by $\overline{\text{OE}}1$ to 3 as shown below.

	LCD PANEL DRIVE OUTPUTS	
OUTPUT ENABLE PIN	LCD PANEL DRIVE <u>PIN</u> S CONTROLLED BY OE	ОИТРИТ
<u>OE</u> 1 = H	G1, G4, G7, ···G250, G253, G256	
OE2 = H	G2, G5, G8, ···G251, G254	V _{OFFR/L}
OE3 = H	G3, G6, G9, ···G252, G255	
OE1 = L	G1, G4, G7, ···G250, G253, G256	Normal
OE2 = L	G2, G5, G8, ···G251, G254	data
OE3 = L	G3, G6, G9, ···G252, G255	output

(3) Voltage setting

The V_{OFFR}/L level, which sets the LCD panel drive's output low level, can take on any value between V_{SS} to V_{SS} + 15 V.

(Example 1) Negative voltage output

Logic input : High = 3.3 V or low = 0 V amplitude

Supply voltage : $V_{GGR} = V_{GGL} = 33 V$

 $V_{DD} = 3.3 V$

 $V_{OFFR} = V_{OFFL} = 0 V$

 $V_{SS} = -7 V$

LCD panel drive output : High level = V_{GGR}/L (33 V)

Low level = V_{OFFR}/L (0 V)

(Example 2) Positive voltage output

Logic input : High = 3.3 V or low = 0 V amplitude

Supply voltage : $V_{GGR} = V_{GGL} = 40 \text{ V}$

 $V_{DD} = 3.3 V$

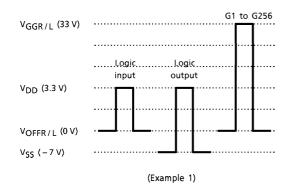
V_{OFFR} = V_{OFFL} = V_{SS} = 0 V

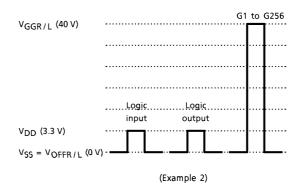
LCD panel drive output : High level = V_{GGR}/L (40 V)

Low level = V_{OFFR}/L (0 V)

(Note) : The logic input here means input pins DI/O, DO/I, CPV and $\overline{OE}1$ to 3.

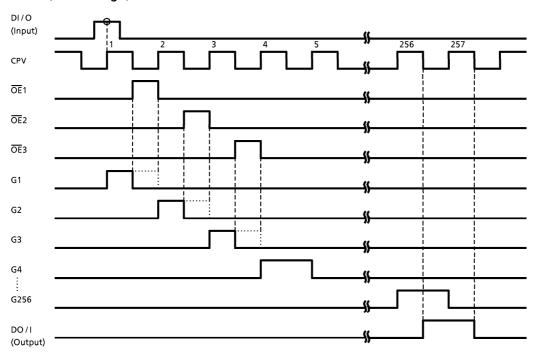
Make sure that the voltage applied to the U/D pin is a high (= V_{DD}) or low (= V_{SS}) DC-level voltage.



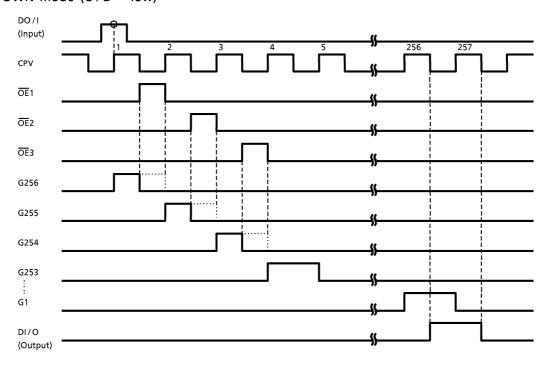


TIMING DIAGRAM

• UP mode (U/D = high)



• DOWN mode (U/D = low)



ABSOLUTE MAXIMUM RATINGS $(V_{SS} = 0 V)$

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	Vggr/L	-0.3 to 45.0	V
Supply Voltage	V_{DD}	-0.3 to 22.0	V
Input Voltage	VIN	-0.3 to $V_{DD} + 0.3$	V
Analog Input Voltage	VOFFR / L	-0.3 to V _{GG} + 0.3	V
Storage Temperature	T _{stg}	- 55 to 125	°C

RECOMMENDED OPERATING CONDITIONS ($V_{SS} = 0 V$)

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	V _{GGR/L}	25.0 to 42.0	V
Supply Voltage	V_{DD}	3.0 to 16.0	V
Operating Temperature	ТОР	-20 to 75	°C
Operating Frequency	f _{CPV}	DC to 100	kHz
Output Load Capacitance	CL	300 (max)	pF/pin
Analog Input Voltage	V _{OFFR} /L	0 to 15.0	V

ELECTRICAL CHARACTERISTICS

DC CHARACTERISTICS $\begin{cases} \text{Referenced to V}_{GGR} = \text{V}_{GGL} = 25 \text{ to } 42 \text{ V}, \text{V}_{DD} = 3.0 \text{ to } 16.0 \text{ V}, \text{V}_{SS} = 0 \text{ V} \\ \text{Ta} = -20 \text{ to } 75^{\circ}\text{C unless otherwise noted} \end{cases}$

PARAMETER		SYMBOL	TEST CIR- CUIT	TEST CONDITIONS	MIN	TYP.	MAX	UNIT	RELEVANT PIN	
Input	Low Level	VIL			V _{SS}	_	V _{DD} - 2.5	V	(*)	
Voltage	High Level	VIH	_	_	V _{DD} - 0.5	_	V _{DD}	V		
Output Voltage	Low Level	VOL	_	I _{OL} = 40 μA	VSS	_	V _S S + 0.3	v	DI/O, DO/I	
	High Level	Voн		I _{OH} = -40 μA	V _{DD} - 0.3	_	V _{DD}	V		
Output Resistance	Low Level	ROL		V _{OUT} = V _{OFFR/L} + 0.5 V				1500	Ω	G1 to G256
	High Level	ROH		$V_{OUT} = V_{GGR/L} - 0.5 V$			1300	4.2	d1 to d230	
Current Consumption		IGG	_	$V_{GGR/L} = 42 V$		_	500	μ A	V _{GGR/L}	
Current Consumption		I _{DD}	_	f _{CPV} = 100 kHz	_	_	1.0	mA	V_{DD}	

(*) : These input pins include DI/O, DO/I, CPV and $\overline{OE}1$ to 3.

AC CHARACTERISTICS (Referenced to $V_{GGR} = V_{GGL} = 25$ to 42 V, $V_{DD} = 3.0$ to 16.0 V, $V_{SS} = 0$ V $T_{a} = -20$ to 75°C unless otherwise noted

PARAMETER	SYMBOL	TEST CIR- CUIT	TEST CONDITIONS	MIN	TYP.	MAX	UNIT
Clock Period	tCPV		_	10	_	_	μs
CPV Pulse Width (H)	tCPVH	_	_	4	_	_	μs
CPV Pulse Width (L)	tCPVL	_	_	4	_	_	μs
Data Set-up Time	tsDI	_	_	1	_	_	μs
Data Hold Time	thDI	_	_	1	_	_	μs
OE Enable Time	twOE	_	_	1	_	_	μs
Output Delay Time (1)	tpdDO	_	$C_L = 50 pF$	_	_	1	μs
Output Delay Time (2)	tpdG	_	$C_L = 300 pF$	_	_	1	μs
Output Delay Time (3)	tpdOE		C _L = 300 pF	_	_	1	μs

